# 74LV595

8-bit serial-in/serial-out or parallel-out shift register; 3-state
Rev. 5 — 29 September 2021 Product data sheet

### 1. General description

The 74LV595 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and 3-state outputs. Both the shift and storage register have separate clocks. The device features a serial input (DS) and a serial output (Q7S) to enable cascading and an asynchronous reset  $\overline{\text{MR}}$  input. A LOW on  $\overline{\text{MR}}$  will reset the shift register. Data is shifted on the LOW-to-HIGH transitions of the SHCP input. The data in the shift register is transferred to the storage register on a LOW-to-HIGH transition of the STCP input. If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register. Data in the storage register appears at the output whenever the output enable input ( $\overline{\text{OE}}$ ) is LOW. A HIGH on  $\overline{\text{OE}}$  causes the outputs to assume a high-impedance OFF-state. Operation of the  $\overline{\text{OE}}$  input does not affect the state of the registers. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess V<sub>CC</sub>.

### 2. Features and benefits

- Wide supply voltage range from 1.0 V to 3.6 V
- · CMOS low power dissipation
- · Direct interface with TTL levels
- Typical output ground bounce < 0.8 V at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C
- Typical HIGH-level output voltage (V<sub>OH</sub>) undershoot: > 2 V at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C
- Has a shift register with direct clear
- Output capability:
  - Parallel outputs; bus driver
  - Serial output; standard
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
- · ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to 85 °C and -40 °C to 125 °C

# 3. Applications

- Serial-to-parallel data conversion
- Remote control holding register



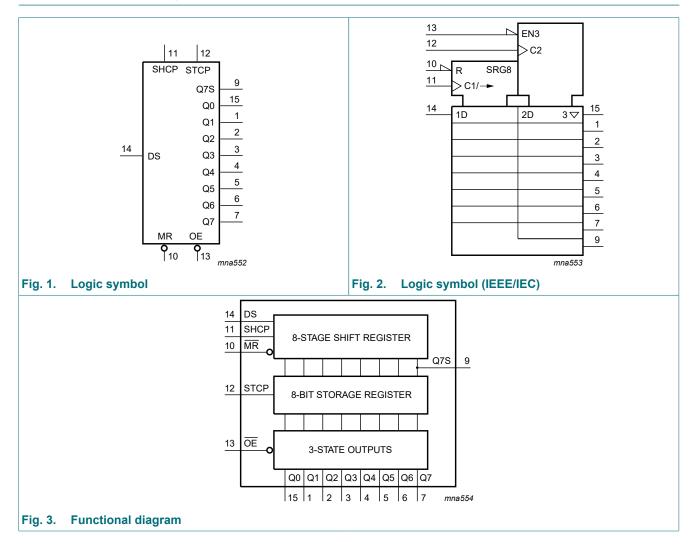
8-bit serial-in/serial-out or parallel-out shift register; 3-state

# 4. Ordering information

**Table 1. Ordering information** 

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74LV595D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						
74LV595PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1						

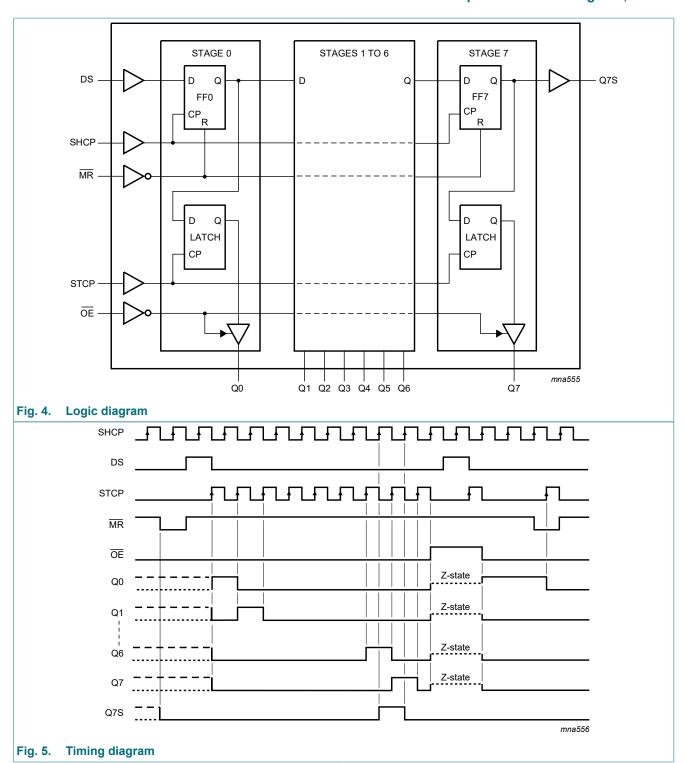
# 5. Functional diagram



**Product data sheet** 

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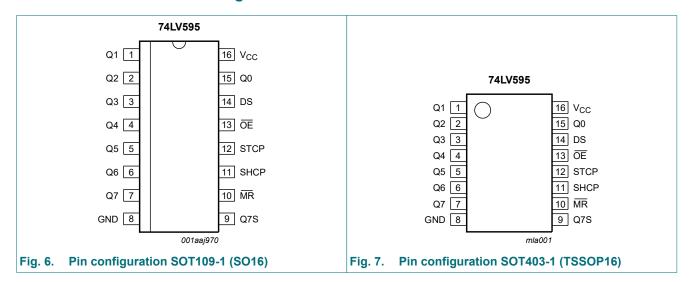
### 8-bit serial-in/serial-out or parallel-out shift register; 3-state



8-bit serial-in/serial-out or parallel-out shift register; 3-state

## 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	15, 1, 2, 3, 4, 5, 6, 7	parallel data output
GND	8	ground (0 V)
Q7S	9	serial data output
MR	10	master reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
ŌE	13	output enable input (active LOW)
DS	14	serial data input
V <sub>CC</sub>	16	supply voltage

8-bit serial-in/serial-out or parallel-out shift register; 3-state

# 7. Functional description

#### Table 3. Function table

 $H = HIGH \ voltage \ state; \ L = LOW \ voltage \ state; \ \uparrow = LOW - to - HIGH \ transition;$ 

X = don't care; NC = no change; Z = high-impedance OFF-state.

Input					Outpu	ıt	Function
SHCP	STCP	OE	MR	DS	Q7S	Qn	
Χ	Х	L	L	Х	L	NC	a LOW-state on MR only affects the shift register
Χ	1	L	L	Х	L	L	empty shift register loaded into storage register
Χ	Х	Н	L	Х	L	Z	shift register clear; parallel outputs in high-impedance OFF-state
1	Х	L	Н	Н	Q6S	NC	logic HIGH-state shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S).
X	1	L	Н	Х	NC	QnS	contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages
<b>↑</b>	1	L	Н	X	Q6S	QnS	contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages

## 8. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±50	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-		
		standard driver outputs		25	mA
		bus driver outputs		35	mA
I <sub>CC</sub>	supply current	standard driver outputs		50	mA
		bus driver outputs		70	mA
I <sub>GND</sub>	ground current	standard driver outputs	-50		mA
		bus driver outputs	-70		mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C to } +125  ^{\circ}\text{C}$ [1]	-	500	mW

<sup>[1]</sup> For SOT109-1 (SO16) package:  $P_{tot}$  derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package:  $P_{tot}$  derates linearly with 8.5 mW/K above 91 °C.

8-bit serial-in/serial-out or parallel-out shift register; 3-state

# 9. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		1.0	3.3	3.6	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.0 V to 2.0 V	-	-	500	ns/V
		V <sub>CC</sub> = 2.0 V to 2.7 V	-	-	200	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	100	ns/V

## 10. Static characteristics

#### **Table 6. Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	Unit	
			Min	Typ [1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 1.2 V	0.9	-	-	0.9	-	V
	voltage	V <sub>CC</sub> = 2.0 V	1.4	-	-	1.4	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 1.2 V		-	0.3	-	0.3	V
	voltage	V <sub>CC</sub> = 2.0 V	-	-	0.6	-	0.6	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V <sub>OH</sub> HIGH-level outp voltage	HIGH-level output voltage	all outputs; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -100 \mu A$						
		V <sub>CC</sub> = 1.2 V	-	1.2	-	-	-	V
		V <sub>CC</sub> = 2.0 V	1.8	2.0	-	1.8	-	V
		V <sub>CC</sub> = 2.7 V	2.5	2.7	-	2.5	-	V
		V <sub>CC</sub> = 3.0 V	2.8	3.0	-	2.8	-	V
		standard outputs; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = -6 mA; V <sub>CC</sub> = 3.0 V	2.4	2.82	-	2.2	-	V
		bus outputs; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -8$ mA; $V_{CC} = 3.0$ V	2.4	2.82	-	2.2	-	V
V <sub>OL</sub>	LOW-level output voltage	all outputs; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 100 \mu A$						
		V <sub>CC</sub> = 1.2 V	-	0	-	-	-	V
		V <sub>CC</sub> = 2.0 V	-	0	0.2	-	0.2	V
		V <sub>CC</sub> = 2.7 V	-	0	0.2	-	0.2	V
		V <sub>CC</sub> = 3.0 V	-	0	0.2	-	0.2	V
		standard driver outputs V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 6 mA	-	0.25	0.4	-	0.5	V
		bus driver outputs $V_{CC}$ = 3.0 V; $I_{O}$ = 8 mA	-	0.20	0.4	-	0.5	V
l <sub>l</sub>	input leakage current	V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 5.5 V or GND	-	-	1.0	-	1.0	μΑ

### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to	Unit	
			Min	Typ [1]	Max	Min	Max	
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 3.6 \text{ V}$	-	-	5	-	10	μΑ
I <sub>CC</sub>	supply current	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} \text{ or GND};$ $I_{O} = 0 \text{ A}$	-	-	20	-	160	μΑ
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_{CC}$ = 2.7 V to 3.6 V; $V_I$ = $V_{CC}$ - 0.6 V	-	-	500	-	850	μΑ
Cı	input capacitance		-	3.5	-	-	-	pF

<sup>[1]</sup> All typical values are measured at  $V_{CC}$  = 3.3 V (unless stated otherwise) and  $T_{amb}$  = 25 °C.

# 11. Dynamic characteristics

**Table 7. Dynamic characteristics** 

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 13.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	-40 °C to	o +125 °C	Unit
				Min	Typ [1]	Max	Min	Max	1
t <sub>pd</sub>	propagation delay	SHCP to Q7S; see Fig. 8	[2]						
		V <sub>CC</sub> = 1.2 V		-	95	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	32	61	-	75	ns
		V <sub>CC</sub> = 2.7 V		-	24	45	-	55	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF		-	15	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	18	36	-	44	ns
		STCP to Qn; see Fig. 9	[2]						
		V <sub>CC</sub> = 1.2 V		-	100	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	34	65	-	77	ns
		V <sub>CC</sub> = 2.7 V		-	25	48	-	56	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF		-	16	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	19	38	-	45	ns
		MR to Q7S; see Fig. 11							
		V <sub>CC</sub> = 1.2 V		-	85	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	29	56	-	66	ns
		V <sub>CC</sub> = 2.7 V		-	21	41	-	49	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF		-	14	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	16	33	-	33	ns
t <sub>en</sub>	enable time	OE to Qn; see Fig. 12	[4]						
		V <sub>CC</sub> = 1.2 V		-	85	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	29	56	-	66	ns
		V <sub>CC</sub> = 2.7 V		-	21	41	-	49	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	16	33	-	39	ns
t <sub>dis</sub>	disable time	OE to Qn; see Fig. 12	[5]						
		V <sub>CC</sub> = 1.2 V		-	65	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		-	24	40	-	49	ns
		V <sub>CC</sub> = 2.7 V		-	18	32	-	37	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	14	26	-	30	ns

## 8-bit serial-in/serial-out or parallel-out shift register; 3-state

Symbol	Parameter	Conditions		-40	°C to +85	°C	-40 °C to	+125 °C	Unit
				Min	Typ [1]	Max	Min	Max	
t <sub>W</sub>	pulse width	SHCP, HIGH or LOW; see Fig. 8							
		V <sub>CC</sub> = 2.0 V		34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V		25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	20	6	-	24	-	ns
		STCP, HIGH or LOW; see Fig. 9							
		V <sub>CC</sub> = 2.0 V		34	7	-	41	-	ns
		V <sub>CC</sub> = 2.7 V		25	5	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	20	4	-	24	-	ns
		MR LOW; see Fig. 11							
		V <sub>CC</sub> = 2.0 V		34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V		25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	20	6	-	24	-	ns
t <sub>su</sub>	set-up time	DS to SHCP; see Fig. 10							
		V <sub>CC</sub> = 1.2 V		-	40	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		26	14	-	31	-	ns
		V <sub>CC</sub> = 2.7 V		19	10	-	23	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	15	8	-	18	-	ns
		SHCP to STCP; see Fig. 9							
		V <sub>CC</sub> = 1.2 V		-	40	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		26	14	-	31	-	ns
		V <sub>CC</sub> = 2.7 V		19	10	-	23	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	15	8	-	18	-	ns
t <sub>h</sub>	hold time	DS to SHCP; see Fig. 10							
		V <sub>CC</sub> = 1.2 V		-	-10.0	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		5.0	-4.0	-	5.0	-	ns
		V <sub>CC</sub> = 2.7 V		5.0	-3.0	-	5.0	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	5.0	-2.0	-	5.0	-	ns
t <sub>rec</sub>	recovery time	MR to SHCP; see Fig. 11							
		V <sub>CC</sub> = 1.2 V		-	-35	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		5.0	-12.0	-	5.0	-	ns
		V <sub>CC</sub> = 2.7 V		5.0	-9.0	-	5.0	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	5.0	-7.0	-	5.0	-	ns
f <sub>max</sub>	maximum frequency	SHCP or STCP; see Fig. 8 and Fig. 9							
		V <sub>CC</sub> = 2.0 V		14.0	40.0	-	12	-	MHz
		V <sub>CC</sub> = 2.7 V		19.0	58.0	-	16	-	MHz
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF		-	77	-	-	-	MHz
			[3]	24.0	70.0	-	20	-	MHz

#### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

Symbol	Parameter	Conditions -40 °C to +85 °C		-40 °C to	Unit			
			Min	Typ [1]	Max	Min	Max	
C <sub>PD</sub>	power dissipation capacitance	$V_1 = GND \text{ to } V_{CC}; V_{CC} = 3.0 \text{ V}$ [6]	-	115	-	-	-	pF

- [1] Typical values are measured at T<sub>amb</sub> = 25 °C.
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [3] Typical value measured at  $V_{CC}$  = 3.3 V.
- [4]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [5]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .
- [6]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

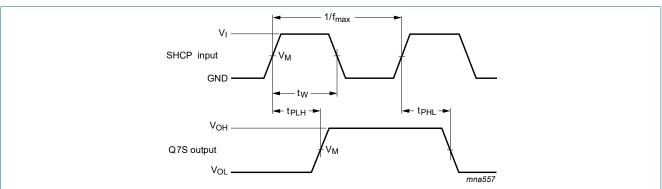
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

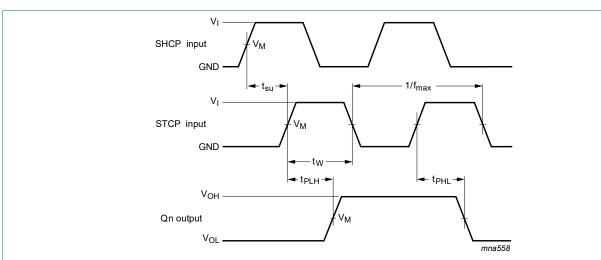
#### 11.1. Waveforms and test circuit



Measurement points are given in Table 8.

 $V_{OL}$  and  $V_{OH}$  are typical output voltage drops that occur with the output load.

Fig. 8. The shift clock (SHCP) to serial data output (Q7S) propagation delays, the shift clock pulse width and maximum shift clock frequency



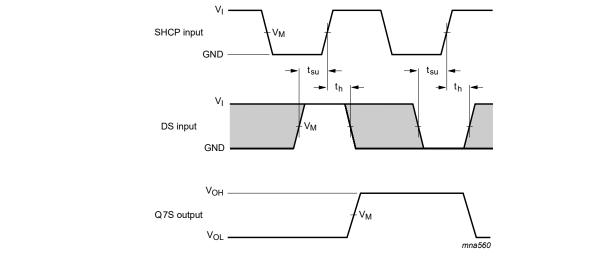
Measurement points are given in Table 8.

 $V_{OL}$  and  $V_{OH}$  are typical output voltage drops that occur with the output load.

Fig. 9. The storage clock (STCP) to parallel data output (Qn) propagation delays, the storage clock pulse width and the shift clock to storage clock set-up time

74LV595

#### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

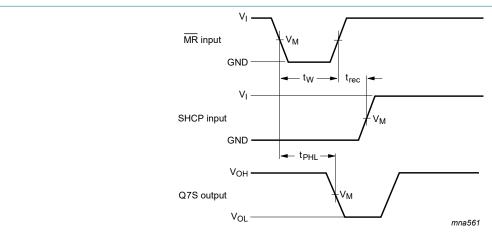


Measurement points are given in Table 8.

The shaded areas indicate when the input is permitted to change for predictable output performance.

V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drops that occur with the output load.

Fig. 10. The data set-up and hold times for the serial data input (DS)



Measurement points are given in Table 8.

 $V_{OL}$  and  $V_{OH}$  are typical output voltage drops that occur with the output load.

Fig. 11. The master reset (MR) pulse width, the master reset to serial data output (Q7S) propagation delays and the master reset to shift clock (SHCP) recovery time

### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

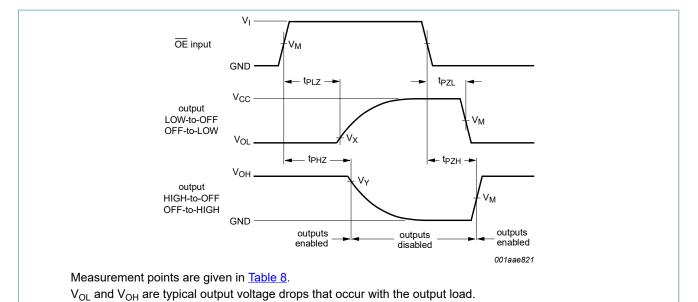
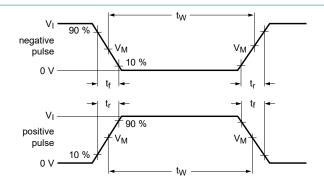


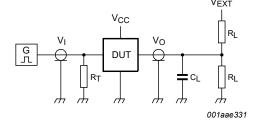
Fig. 12. Enable and disable times

**Table 8. Measurement points** 

Supply voltage	Input	Output						
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>				
V <sub>CC</sub> < 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.1V <sub>CC</sub>	V <sub>OH</sub> - 0.1V <sub>CC</sub>				
V <sub>CC</sub> ≥ 2.7 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V				

### 8-bit serial-in/serial-out or parallel-out shift register; 3-state





Test data is given in Table 9.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

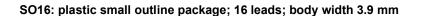
Fig. 13. Test circuit for measuring switching times

Table 9. Test data

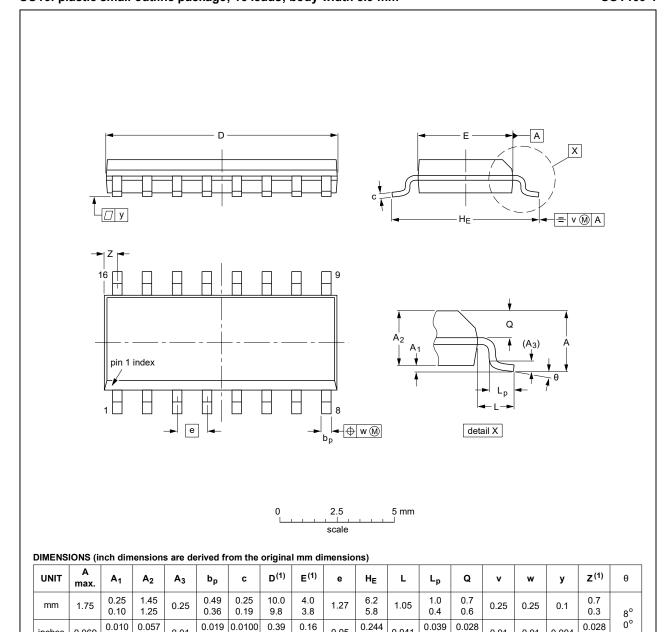
Supply voltage	Input	Load			V <sub>EXT</sub>			
V <sub>CC</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PHZ</sub> , t <sub>PZH</sub>	
< 2.7 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	1 kΩ	open	2V <sub>CC</sub>	GND	
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	1 kΩ	open	2V <sub>CC</sub>	GND	

#### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

# 12. Package outline



SOT109-1



#### inches 0.069

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.014 0.0075

0.38

0.15

0.01

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

0.05

0.041

0.016

0.020

0.228

0.01

0.01

0.004

0.012

Fig. 14. Package outline SOT109-1 (SO16)

0.004

0.049

**Product data sheet** 

### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

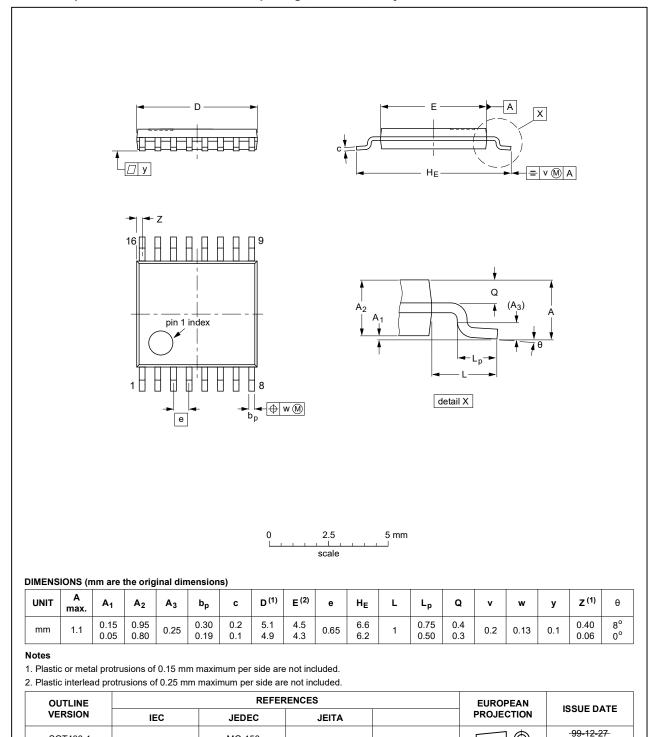


Fig. 15. Package outline SOT403-1 (TSSOP16)

MO-153

Downloaded from Arrow.com.

03-02-18

SOT403-1

### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

## 13. Abbreviations

#### **Table 10. Abbreviations**

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

#### **Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LV595 v.5	20210929	Product data sheet	-	74LV595 v.4		
Modifications:	guidelines Legal texts Type numb Section 1	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74LV595DB (SOT338-1/SSOP16) removed.</li> <li>Section 1 and Section 2 updated.</li> <li>Section 8: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>				
74LV595 v.4	20160318	Product data sheet	-	74LV595 v.3		
Modifications:	Type numb	Type number 74LV595N (SOT38-4) removed.				
74LV595 v.3	20090421	Product data sheet	-	74LV595 v.2		
Modifications:	guidelines	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
74LV595 v.2	980402	Product data sheet	-	74LV595 v.1		
74LV595 v.1	970606	Product data sheet	-	-		

#### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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74LV595

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### 8-bit serial-in/serial-out or parallel-out shift register; 3-state

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